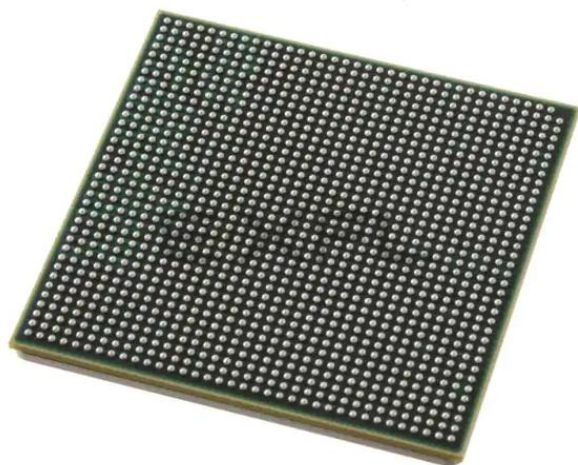




Welcome to [E-XFL.COM](#)

Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	PowerPC e5500
Number of Cores/Bus Width	2 Core, 64-Bit
Speed	2.0GHz
Co-Processors/DSP	-
RAM Controllers	DDR3, DDR3L
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	1Gbps (10), 10Gbps (2)
SATA	SATA 3Gbps (2)
USB	USB 2.0 + PHY (2)
Voltage - I/O	1.0V, 1.1V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	Boot Security, Cryptography, Secure Fusebox, Secure Debug, Tamper Detection, Volatile key Storage
Package / Case	1295-BBGA, FCBGA
Supplier Device Package	1295-FCPBGA (37.5x37.5)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/p5021nx7vnc

Pin assignments and reset states

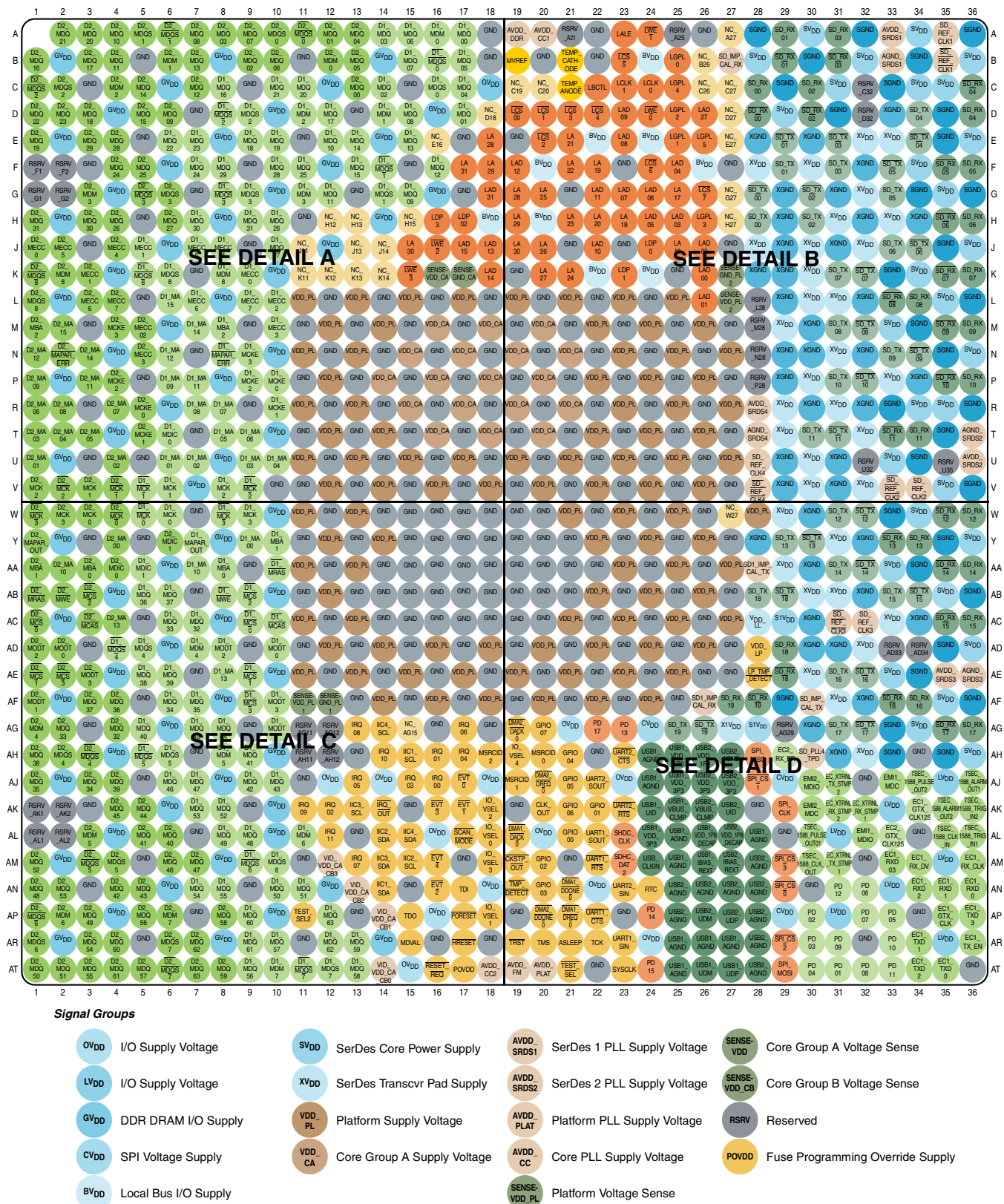


Figure 2. 1295 BGA ball map diagram (top view)

1.2 Pinout list

This table provides the pinout listing for the 1295 FC-PBGA package by bus.

Table 1. Pins listed by bus

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
DDR SDRAM Memory interface 1					
D1_MDQ00	Data	A17	I/O	GV _{DD}	—
D1_MDQ01	Data	D17	I/O	GV _{DD}	—
D1_MDQ02	Data	C14	I/O	GV _{DD}	—
D1_MDQ03	Data	A14	I/O	GV _{DD}	—
D1_MDQ04	Data	C17	I/O	GV _{DD}	—
D1_MDQ05	Data	B17	I/O	GV _{DD}	—
D1_MDQ06	Data	A15	I/O	GV _{DD}	—
D1_MDQ07	Data	B15	I/O	GV _{DD}	—
D1_MDQ08	Data	D15	I/O	GV _{DD}	—
D1_MDQ09	Data	G15	I/O	GV _{DD}	—
D1_MDQ10	Data	E12	I/O	GV _{DD}	—
D1_MDQ11	Data	G12	I/O	GV _{DD}	—
D1_MDQ12	Data	F16	I/O	GV _{DD}	—
D1_MDQ13	Data	E15	I/O	GV _{DD}	—
D1_MDQ14	Data	E13	I/O	GV _{DD}	—
D1_MDQ15	Data	F13	I/O	GV _{DD}	—
D1_MDQ16	Data	C8	I/O	GV _{DD}	—
D1_MDQ17	Data	D12	I/O	GV _{DD}	—
D1_MDQ18	Data	E9	I/O	GV _{DD}	—
D1_MDQ19	Data	E10	I/O	GV _{DD}	—
D1_MDQ20	Data	C11	I/O	GV _{DD}	—
D1_MDQ21	Data	C10	I/O	GV _{DD}	—
D1_MDQ22	Data	E6	I/O	GV _{DD}	—
D1_MDQ23	Data	E7	I/O	GV _{DD}	—
D1_MDQ24	Data	F7	I/O	GV _{DD}	—
D1_MDQ25	Data	F11	I/O	GV _{DD}	—
D1_MDQ26	Data	H10	I/O	GV _{DD}	—
D1_MDQ27	Data	J10	I/O	GV _{DD}	—
D1_MDQ28	Data	F10	I/O	GV _{DD}	—
D1_MDQ29	Data	F8	I/O	GV _{DD}	—
D1_MDQ30	Data	H7	I/O	GV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
SD_TX15	Transmit Data (positive)	AB33	O	XV _{DD}	—
SD_TX14	Transmit Data (positive)	AA31	O	XV _{DD}	—
SD_TX13	Transmit Data (positive)	Y29	O	XV _{DD}	—
SD_TX12	Transmit Data (positive)	W31	O	XV _{DD}	—
SD_TX11	Transmit Data (positive)	T30	O	XV _{DD}	—
SD_TX10	Transmit Data (positive)	P31	O	XV _{DD}	—
SD_TX09	Transmit Data (positive)	N33	O	XV _{DD}	—
SD_TX08	Transmit Data (positive)	M31	O	XV _{DD}	—
SD_TX07	Transmit Data (positive)	K31	O	XV _{DD}	—
SD_TX06	Transmit Data (positive)	J33	O	XV _{DD}	—
SD_TX05	Transmit Data (positive)	G33	O	XV _{DD}	—
SD_TX04	Transmit Data (positive)	D34	O	XV _{DD}	—
SD_TX03	Transmit Data (positive)	F31	O	XV _{DD}	—
SD_TX02	Transmit Data (positive)	H30	O	XV _{DD}	—
SD_TX01	Transmit Data (positive)	F29	O	XV _{DD}	—
SD_TX00	Transmit Data (positive)	H28	O	XV _{DD}	—
$\overline{\text{SD_TX19}}$	Transmit Data (negative)	AG26	O	XV _{DD}	—
$\overline{\text{SD_TX18}}$	Transmit Data (negative)	AB29	O	XV _{DD}	—
$\overline{\text{SD_TX17}}$	Transmit Data (negative)	AG32	O	XV _{DD}	—
$\overline{\text{SD_TX16}}$	Transmit Data (negative)	AE32	O	XV _{DD}	—
$\overline{\text{SD_TX15}}$	Transmit Data (negative)	AB34	O	XV _{DD}	—
$\overline{\text{SD_TX14}}$	Transmit Data (negative)	AA32	O	XV _{DD}	—
$\overline{\text{SD_TX13}}$	Transmit Data (negative)	Y30	O	XV _{DD}	—
$\overline{\text{SD_TX12}}$	Transmit Data (negative)	W32	O	XV _{DD}	—
$\overline{\text{SD_TX11}}$	Transmit Data (negative)	T31	O	XV _{DD}	—
$\overline{\text{SD_TX10}}$	Transmit Data (negative)	P32	O	XV _{DD}	—
$\overline{\text{SD_TX09}}$	Transmit Data (negative)	N34	O	XV _{DD}	—
$\overline{\text{SD_TX08}}$	Transmit Data (negative)	M32	O	XV _{DD}	—
$\overline{\text{SD_TX07}}$	Transmit Data (negative)	K32	O	XV _{DD}	—
$\overline{\text{SD_TX06}}$	Transmit Data (negative)	J34	O	XV _{DD}	—
$\overline{\text{SD_TX05}}$	Transmit Data (negative)	F33	O	XV _{DD}	—
$\overline{\text{SD_TX04}}$	Transmit Data (negative)	E34	O	XV _{DD}	—
$\overline{\text{SD_TX03}}$	Transmit Data (negative)	E31	O	XV _{DD}	—
$\overline{\text{SD_TX02}}$	Transmit Data (negative)	G30	O	XV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
SD_TX01	Transmit Data (negative)	E29	O	XV _{DD}	—
SD_TX00	Transmit Data (negative)	G28	O	XV _{DD}	—
SD_RX19	Receive Data (positive)	AF27	I	XV _{DD}	—
SD_RX18	Receive Data (positive)	AD29	I	XV _{DD}	—
SD_RX17	Receive Data (positive)	AG36	I	XV _{DD}	—
SD_RX16	Receive Data (positive)	AF34	I	XV _{DD}	—
SD_RX15	Receive Data (positive)	AC36	I	XV _{DD}	—
SD_RX14	Receive Data (positive)	AA36	I	XV _{DD}	—
SD_RX13	Receive Data (positive)	Y34	I	XV _{DD}	—
SD_RX12	Receive Data (positive)	W36	I	XV _{DD}	—
SD_RX11	Receive Data (positive)	T34	I	XV _{DD}	—
SD_RX10	Receive Data (positive)	P36	I	XV _{DD}	—
SD_RX09	Receive Data (positive)	M36	I	XV _{DD}	—
SD_RX08	Receive Data (positive)	L34	I	XV _{DD}	—
SD_RX07	Receive Data (positive)	K36	I	XV _{DD}	—
SD_RX06	Receive Data (positive)	H36	I	XV _{DD}	—
SD_RX05	Receive Data (positive)	F36	I	XV _{DD}	—
SD_RX04	Receive Data (positive)	D36	I	XV _{DD}	—
SD_RX03	Receive Data (positive)	A31	I	XV _{DD}	—
SD_RX02	Receive Data (positive)	C30	I	XV _{DD}	—
SD_RX01	Receive Data (positive)	A29	I	XV _{DD}	—
SD_RX00	Receive Data (positive)	C28	I	XV _{DD}	—
$\overline{\text{SD_RX19}}$	Receive Data (negative)	AF28	I	XV _{DD}	—
$\overline{\text{SD_RX18}}$	Receive Data (negative)	AE29	I	XV _{DD}	—
$\overline{\text{SD_RX17}}$	Receive Data (negative)	AG35	I	XV _{DD}	—
$\overline{\text{SD_RX16}}$	Receive Data (negative)	AF33	I	XV _{DD}	—
$\overline{\text{SD_RX15}}$	Receive Data (negative)	AC35	I	XV _{DD}	—
$\overline{\text{SD_RX14}}$	Receive Data (negative)	AA35	I	XV _{DD}	—
$\overline{\text{SD_RX13}}$	Receive Data (negative)	Y33	I	XV _{DD}	—
$\overline{\text{SD_RX12}}$	Receive Data (negative)	W35	I	XV _{DD}	—
$\overline{\text{SD_RX11}}$	Receive Data (negative)	T33	I	XV _{DD}	—
$\overline{\text{SD_RX10}}$	Receive Data (negative)	P35	I	XV _{DD}	—
$\overline{\text{SD_RX09}}$	Receive Data (negative)	M35	I	XV _{DD}	—
$\overline{\text{SD_RX08}}$	Receive Data (negative)	L33	I	XV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
SD_RX07	Receive Data (negative)	K35	I	XV _{DD}	—
SD_RX06	Receive Data (negative)	H35	I	XV _{DD}	—
SD_RX05	Receive Data (negative)	F35	I	XV _{DD}	—
SD_RX04	Receive Data (negative)	C36	I	XV _{DD}	—
SD_RX03	Receive Data (negative)	B31	I	XV _{DD}	—
SD_RX02	Receive Data (negative)	D30	I	XV _{DD}	—
SD_RX01	Receive Data (negative)	B29	I	XV _{DD}	—
SD_RX00	Receive Data (negative)	D28	I	XV _{DD}	—
SD_REF_CLK1	SerDes Bank 1 PLL Reference Clock	A35	I	XV _{DD}	—
SD_REF_CLK1	SerDes Bank 1 PLL Reference Clock Complement	B35	I	XV _{DD}	—
SD_REF_CLK2	SerDes Bank 2 PLL Reference Clock	V34	I	XV _{DD}	—
SD_REF_CLK2	SerDes Bank 2 PLL Reference Clock Complement	V33	I	XV _{DD}	—
SD_REF_CLK3	SerDes Bank 3 PLL Reference Clock	AC32	I	XV _{DD}	—
SD_REF_CLK3	SerDes Bank 3 PLL Reference Clock Complement	AC31	I	XV _{DD}	—
SD_REF_CLK4	SerDes Bank 4 PLL Reference Clock	U28	I	XV _{DD}	—
SD_REF_CLK4	SerDes Bank 4 PLL Reference Clock Complement	V28	I	XV _{DD}	—
General-Purpose Input/Output					
GPIO00	General Purpose Input / Output	AL21	I/O	OV _{DD}	—
GPIO01	General Purpose Input / Output	AK22	I/O	OV _{DD}	—
GPIO02	General Purpose Input / Output	AM20	I/O	OV _{DD}	—
GPIO03	General Purpose Input / Output	AN20	I/O	OV _{DD}	—
GPIO04/USB1_DRVVBUS	General Purpose Input / Output	AH21	I/O	OV _{DD}	—
GPIO05/USB1_PWRFAULT	General Purpose Input / Output	AJ21	I/O	OV _{DD}	—
GPIO06/USB2_DRVVBUS	General Purpose Input / Output	AK21	I/O	OV _{DD}	—
GPIO07/USB2_PWRFAULT	General Purpose Input / Output	AG20	I/O	OV _{DD}	—
GPIO08/UART1_SOUT	General Purpose Input / Output	AL22	I/O	OV _{DD}	—
GPIO09/UART2_SOUT	General Purpose Input / Output	AJ22	I/O	OV _{DD}	—
GPIO10/UART1_SIN	General Purpose Input / Output	AR23	I/O	OV _{DD}	—
GPIO11/UART2_SIN	General Purpose Input / Output	AN23	I/O	OV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
GND	Ground	T13	—	—	—
GND	Ground	V13	—	—	—
GND	Ground	Y13	—	—	—
GND	Ground	AB13	—	—	—
GND	Ground	AD13	—	—	—
GND	Ground	AE14	—	—	—
GND	Ground	AC14	—	—	—
GND	Ground	AA14	—	—	—
GND	Ground	W14	—	—	—
GND	Ground	U14	—	—	—
GND	Ground	R14	—	—	—
GND	Ground	N14	—	—	—
GND	Ground	L14	—	—	—
GND	Ground	M15	—	—	—
GND	Ground	P15	—	—	—
GND	Ground	T15	—	—	—
GND	Ground	V15	—	—	—
GND	Ground	Y15	—	—	—
GND	Ground	AB15	—	—	—
GND	Ground	AD15	—	—	—
GND	Ground	AF15	—	—	—
GND	Ground	W16	—	—	—
GND	Ground	AC16	—	—	—
GND	Ground	AA16	—	—	—
GND	Ground	AE16	—	—	—
GND	Ground	U16	—	—	—
GND	Ground	R16	—	—	—
GND	Ground	N16	—	—	—
GND	Ground	M17	—	—	—
GND	Ground	P17	—	—	—
GND	Ground	T17	—	—	—
GND	Ground	N18	—	—	—
GND	Ground	R18	—	—	—
GND	Ground	U18	—	—	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
GND	Ground	Y17	—	—	—
GND	Ground	AB17	—	—	—
GND	Ground	AD17	—	—	—
GND	Ground	AF17	—	—	—
GND	Ground	W18	—	—	—
GND	Ground	AC18	—	—	—
GND	Ground	AA18	—	—	—
GND	Ground	AE18	—	—	—
GND	Ground	AF19	—	—	—
GND	Ground	AD19	—	—	—
GND	Ground	AB19	—	—	—
GND	Ground	Y19	—	—	—
GND	Ground	V19	—	—	—
GND	Ground	T19	—	—	—
GND	Ground	P19	—	—	—
GND	Ground	M19	—	—	—
GND	Ground	N20	—	—	—
GND	Ground	R20	—	—	—
GND	Ground	U20	—	—	—
GND	Ground	AE20	—	—	—
GND	Ground	AA20	—	—	—
GND	Ground	AC20	—	—	—
GND	Ground	W20	—	—	—
GND	Ground	AF21	—	—	—
GND	Ground	AD21	—	—	—
GND	Ground	AB21	—	—	—
GND	Ground	Y21	—	—	—
GND	Ground	V21	—	—	—
GND	Ground	T21	—	—	—
GND	Ground	P21	—	—	—
GND	Ground	M21	—	—	—
GND	Ground	AE22	—	—	—
GND	Ground	AC22	—	—	—
GND	Ground	AA22	—	—	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
USB1_AGND	USB1 PHY Transceiver GND	AR26	—	—	—
USB1_AGND	USB1 PHY Transceiver GND	AR27	—	—	—
USB1_AGND	USB1 PHY Transceiver GND	AR28	—	—	—
USB1_AGND	USB1 PHY Transceiver GND	AT25	—	—	—
USB1_AGND	USB1 PHY Transceiver GND	AT28	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AH27	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AL28	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AM28	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AN25	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AN26	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AN27	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AN28	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AP25	—	—	—
USB2_AGND	USB2 PHY Transceiver GND	AP28	—	—	—
OVDD	General I/O Supply	AN22	—	OV _{DD}	—
OVDD	General I/O Supply	AJ14	—	OV _{DD}	—
OVDD	General I/O Supply	AJ18	—	OV _{DD}	—
OVDD	General I/O Supply	AL16	—	OV _{DD}	—
OVDD	General I/O Supply	AJ12	—	OV _{DD}	—
OVDD	General I/O Supply	AN18	—	OV _{DD}	—
OVDD	General I/O Supply	AG21	—	OV _{DD}	—
OVDD	General I/O Supply	AL20	—	OV _{DD}	—
OVDD	General I/O Supply	AT15	—	OV _{DD}	—
OVDD	General I/O Supply	AJ23	—	OV _{DD}	—
OVDD	General I/O Supply	AP16	—	OV _{DD}	—
OVDD	General I/O Supply	AR24	—	OV _{DD}	—
CVDD	eSPI & eSDHC Supply	AG24	—	CV _{DD}	—
CVDD	eSPI & eSDHC Supply	AJ29	—	CV _{DD}	—
CVDD	eSPI & eSDHC Supply	AP29	—	CV _{DD}	—
GVDD	DDR Supply	B2	—	GV _{DD}	—
GVDD	DDR Supply	B8	—	GV _{DD}	—
GVDD	DDR Supply	B14	—	GV _{DD}	—
GVDD	DDR Supply	C18	—	GV _{DD}	—
GVDD	DDR Supply	C12	—	GV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
GVDD	DDR Supply	C6	—	GV _{DD}	—
GVDD	DDR Supply	D4	—	GV _{DD}	—
GVDD	DDR Supply	D10	—	GV _{DD}	—
GVDD	DDR Supply	D16	—	GV _{DD}	—
GVDD	DDR Supply	E14	—	GV _{DD}	—
GVDD	DDR Supply	E8	—	GV _{DD}	—
GVDD	DDR Supply	E2	—	GV _{DD}	—
GVDD	DDR Supply	F6	—	GV _{DD}	—
GVDD	DDR Supply	F12	—	GV _{DD}	—
GVDD	DDR Supply	AR8	—	GV _{DD}	—
GVDD	DDR Supply	G4	—	GV _{DD}	—
GVDD	DDR Supply	G10	—	GV _{DD}	—
GVDD	DDR Supply	G16	—	GV _{DD}	—
GVDD	DDR Supply	H14	—	GV _{DD}	—
GVDD	DDR Supply	H8	—	GV _{DD}	—
GVDD	DDR Supply	H2	—	GV _{DD}	—
GVDD	DDR Supply	J6	—	GV _{DD}	—
GVDD	DDR Supply	K10	—	GV _{DD}	—
GVDD	DDR Supply	K4	—	GV _{DD}	—
GVDD	DDR Supply	L2	—	GV _{DD}	—
GVDD	DDR Supply	L8	—	GV _{DD}	—
GVDD	DDR Supply	M6	—	GV _{DD}	—
GVDD	DDR Supply	N4	—	GV _{DD}	—
GVDD	DDR Supply	N10	—	GV _{DD}	—
GVDD	DDR Supply	P8	—	GV _{DD}	—
GVDD	DDR Supply	P2	—	GV _{DD}	—
GVDD	DDR Supply	R6	—	GV _{DD}	—
GVDD	DDR Supply	T10	—	GV _{DD}	—
GVDD	DDR Supply	T4	—	GV _{DD}	—
GVDD	DDR Supply	J12	—	GV _{DD}	—
GVDD	DDR Supply	U2	—	GV _{DD}	—
GVDD	DDR Supply	U8	—	GV _{DD}	—
GVDD	DDR Supply	V7	—	GV _{DD}	—
GVDD	DDR Supply	AK10	—	GV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
BVDD	Local Bus Supply	E22	—	BV _{DD}	—
BVDD	Local Bus Supply	K24	—	BV _{DD}	—
BVDD	Local Bus Supply	H20	—	BV _{DD}	—
BVDD	Local Bus Supply	H18	—	BV _{DD}	—
SVDD	SerDes Core Logic Supply	A30	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	A34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AA33	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AB35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AD36	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AE33	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AF35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AG34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	B28	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	B32	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	B36	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	C31	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	C34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	C35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	D29	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	E36	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	F34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	G35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	J36	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	K34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	L35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	M33	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	N36	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	R34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	R35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	U33	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	V35	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	W34	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	Y36	—	SV _{DD}	—
SVDD	SerDes Core Logic Supply	AH36	—	SV _{DD}	—

Table 1. Pins listed by bus (continued)

Signal	Signal description	Package pin number	Pin type	Power supply	Notes
AVDD_SRDS2	SerDes PLL2 Supply	U36	—	—	13
AVDD_SRDS3	SerDes PLL3 Supply	AE35	—	—	13
AVDD_SRDS4	SerDes PLL4 Supply	R28	—	—	13
SENSEVDD_PL1	Platform Vdd Sense	AF11	—	—	8
SENSEVDD_PL2	Platform Vdd Sense	L27	—	—	8
SENSEVDD_CA	Core Group A Vdd Sense	K16	—	—	8
USB1_VDD_3P3	USB1 PHY Transceiver 3.3V Supply	AL24	—	—	—
USB1_VDD_3P3	USB1 PHY Transceiver 3.3V Supply	AJ25	—	—	—
USB2_VDD_3P3	USB2 PHY Transceiver 3.3V Supply	AJ26	—	—	—
USB2_VDD_3P3	USB2 PHY Transceiver 3.3V Supply	AJ27	—	—	—
USB1_VDD_1P0	USB1 PHY PLL 1.0V Supply	AH25	—	—	—
USB2_VDD_1P0	USB2 PHY PLL 1.0V Supply	AH26	—	—	—
Analog Signals					
MVREF	SSTL_1.5/1.35 Reference Voltage	B19	I	$GV_{DD}/2$	—
SD_IMP_CAL_TX	SerDes transmitter Impedance Calibration	AF30	I	200Ω ($\pm 1\%$) to XV_{DD}	23
SD1_IMP_CAL_TX	SerDes transmitter Impedance Calibration	AA28	I	200Ω ($\pm 1\%$) to XV_{DD}	23
SD_IMP_CAL_RX	SerDes receiver Impedance Calibration	B27	I	200Ω ($\pm 1\%$) to SV_{DD}	24
SD1_IMP_CAL_RX	SerDes receiver Impedance Calibration	AF26	I	200Ω ($\pm 1\%$) to SV_{DD}	24
TEMP_ANODE	Temperature Diode Anode	C21	—	internal diode	9
TEMP_CATHODE	Temperature Diode Cathode	B21	—	internal diode	9
USB1_IBIAS_REXT	USB PHY1 Reference Bias Current Generation	AM26	—	—	36
USB2_IBIAS_REXT	USB PHY2 Reference Bias Current Generation	AM27	—	—	36
USB1_VDD_1P8_DECAP	USB1 PHY 1.8V Output to External Decap	AL26	—	—	37

2.1.2 Recommended operating conditions

This table provides the recommended operating conditions for this device. Note that proper device operation outside these conditions is not guaranteed.

Table 3. Recommended operating conditions

Parameter		Symbol	Recommended value	Unit	Notes
Core group A (core 0,1) supply voltage		V_{DD_CA}	1.1 ± 50mV (core frequency ≤ 2000 MHz) 1.2V ± 30mV (core frequency > 2000 MHz)	V	1,6
Platform supply voltage		V_{DD_PL}	1.0 ± 50mV	V	1,6
PLL supply voltage (core, platform, DDR, FMan)		AV_{DD}	1.0 ± 50mV	V	—
PLL supply voltage (SerDes)		AV_{DD_SRDS}	1.0 ± 50mV	V	—
Fuse programming override supply		POV_{DD}	1.5 ± 75mV	V	2
DUART, I ² C, DMA, MPIC, GPIO, system control and power management, clocking, debug, I/O voltage select, and JTAG I/O voltage		OV_{DD}	3.3 ± 165mV	V	—
eSPI, eSDHC		CV_{DD}	3.3 ± 165mV 2.5 ± 125mV 1.8 ± 90mV	V	—
DDR DRAM I/O voltage	DDR3	GV_{DD}	1.5 ± 75mV	V	—
	DDR3L		1.35 ± 67mV		
Enhanced local bus I/O voltage		BV_{DD}	3.3 ± 165mV 2.5 ± 125mV 1.8 ± 90mV	V	—
Main power supply for internal circuitry of SerDes and pad power supply for SerDes receiver		SV_{DD}	1.0 + 50mV 1.0 – 30mV	V	—
Pad power supply for SerDes transmitter		XV_{DD}	1.8 ± 90mV 1.5 ± 75mV	V	—
Ethernet I/O, Ethernet Management interface 1 (EMI1), 1588, GPIO		LV_{DD}	3.3 ± 165mV 2.5 ± 125mV	V	3
USB PHY transceiver supply voltage		$USB_V_{DD_3P3}$	3.3 ± 165mV	V	—
USB PHY PLL supply voltage		$USB_V_{DD_1P0}$	1.0 ± 50mV	V	—
Low-power security monitor supply		V_{DD_LP}	1.0 ± 50mV	V	—

Table 3. Recommended operating conditions (continued)

Parameter		Symbol	Recommended value	Unit	Notes
Input voltage	DDR3 and DDR3L DRAM signals	MV_{IN}	GND to GV_{DD}	V	7
	DDR3 and DDR3L DRAM reference	MV_{REF}	$GV_{DD}/2 \pm 1\%$	V	7
	Ethernet signals (except EMI2)	LV_{IN}	GND to LV_{DD}	V	7
	eSPI, eSHDC	CV_{IN}	GND to CV_{DD}	V	7
	Enhanced local bus signals	BV_{IN}	GND to BV_{DD}	V	7
	DUART, I ² C, DMA, MPIC, GPIO, system control and power management, clocking, debug, I/O voltage select, and JTAG I/O voltage	OV_{IN}	GND to OV_{DD}	V	7
	SerDes signals	SV_{IN}	GND to SV_{DD}	V	7
	USB PHY Transceiver signals	USB_V_{IN-3P3}	GND to USB_V_{DD-3P3}	V	7
	Ethernet Management interface 2 (EMI2) signals	—	GND to 1.2V	V	4, 7
Operating Temperature range	Normal Operation	T_A , T_J	$T_A = 0$ (min) to $T_J = 105$ (max) (90 (max) core frequency > 2000 MHz)	°C	—
	Extended Temperature	T_A , T_J	$T_A = -40$ (min) to $T_J = 105$ (max)	°C	—
	Secure Boot Fuse Programming	T_A , T_J	$T_A = 0$ (min) to $T_J = 70$ (max)	°C	2

Notes:

1. V_{DD_PL} voltage must not exceed V_{DD_CA} .
2. POV_{DD} must be supplied 1.5 V and the chip must operate in the specified fuse programming temperature range only during secure boot fuse programming. For all other operating conditions, POV_{DD} must be tied to GND, subject to the power sequencing constraints shown in [Section 2.2, "Power-up sequencing."](#)
3. Selecting RGMII limits LV_{DD} to 2.5V.
4. Ethernet Management interface 2 pins function as open drain I/Os. The interface shall conform to 1.2 V nominal voltage levels. LV_{DD} must be powered to use this interface.
6. Supply voltage specified at the voltage sense pin. Voltage input pins must be regulated to provide specified voltage at the sense pin.
7. All input signals must increase/decrease monotonically throughout the entire rise/fall duration.

Electrical characteristics

This table provides the system clock (SYSCLK) AC timing specifications.

Table 12. SYSCLK AC timing specifications

For recommended operating conditions, see [Table 3](#).

Parameter/Condition	Symbol	Min	Typ	Max	Unit	Notes
SYSCLK frequency	f_{SYSCLK}	100	—	166	MHz	1, 2
SYSCLK cycle time	t_{SYSCLK}	6	—	10	ns	1, 2
SYSCLK duty cycle	$t_{\text{KHK}} / t_{\text{SYSCLK}}$	40	—	60	%	2
SYSCLK slew rate	—	1	—	4	V/ns	3
SYSCLK peak period jitter	—	—	—	150	ps	—
SYSCLK jitter phase noise	—	—	—	500	KHz	4
AC Input Swing Limits at 3.3 V OV_{DD}	ΔV_{AC}	1.9	—	—	V	—

Notes:

- Caution:** The relevant clock ratio settings must be chosen such that the resulting SYSCLK frequency, do not exceed their respective maximum or minimum operating frequencies.
- Measured at the rising edge and/or the falling edge at $OV_{\text{DD}}/2$.
- Slew rate as measured from $\pm 0.3 \Delta V_{\text{AC}}$ at center of peak to peak voltage at clock input.
- Phase noise is calculated as FFT of TIE jitter.

2.6.2 Spread-spectrum sources recommendations

Spread-spectrum clock sources is an increasingly popular way to control electromagnetic interference emissions (EMI) by spreading the emitted noise to a wider spectrum and reducing the peak noise magnitude in order to meet industry and government requirements. These clock sources intentionally add long-term jitter to diffuse the EMI spectral content. The jitter specification given in [Table 13](#) considers short-term (cycle-to-cycle) jitter only. The clock generator's cycle-to-cycle output jitter should meet the chip's input cycle-to-cycle jitter requirement. Frequency modulation and spread are separate concerns; the chip is compatible with spread spectrum sources if the recommendations listed in [Table 13](#) are observed.

Table 13. Spread-spectrum clock source recommendations

For recommended operating conditions, see [Table 3](#).

Parameter	Min	Max	Unit	Notes
Frequency modulation	—	60	kHz	—
Frequency spread	—	1.0	%	1, 2

Notes:

- SYSCLK frequencies that result from frequency spreading and the resulting core frequency must meet the minimum and maximum specifications given in [Table 12](#).
- Maximum spread spectrum frequency may not result in exceeding any maximum operating frequency of the device.

CAUTION

The processor's minimum and maximum SYSCLK and core/platform/DDR frequencies must not be exceeded regardless of the type of clock source. Therefore, systems in which the processor is operated at its maximum rated core/platform/DDR frequency should avoid violating the stated limits by using down-spreading only.

This table provides the MII transmit AC timing specifications.

Table 34. MII transmit AC timing specifications

For recommended operating conditions, see [Table 3](#).

Parameter	Symbol	Min	Typ	Max	Unit
TX_CLK clock period 10 Mbps	t_{MTX}	399.96	400	400.04	ns
TX_CLK clock period 100 Mbps	t_{MTX}	39.996	40	40.004	ns
TX_CLK duty cycle	t_{MTXH}/t_{MTX}	35	—	65	%
TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay	t_{MTKHDX}	0	—	25	ns
TX_CLK data clock rise (20%–80%)	t_{MTXR}	1.0	—	4.0	ns
TX_CLK data clock fall (80%–20%)	t_{MTXF}	1.0	—	4.0	ns

This figure shows the MII transmit AC timing diagram.

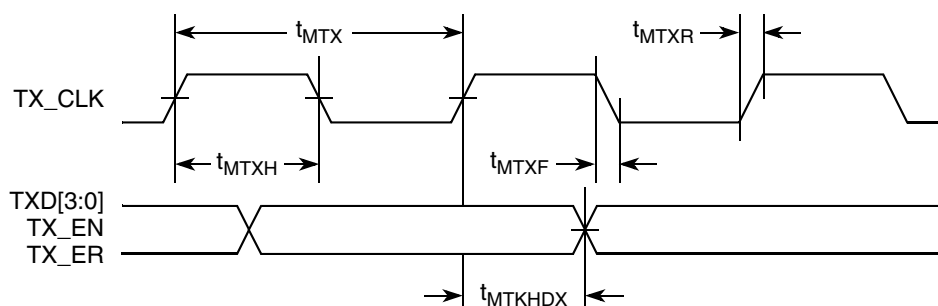


Figure 15. MII transmit AC timing diagram

This table provides the MII receive AC timing specifications.

Table 35. MII Receive AC timing specifications

For recommended operating conditions, see [Table 3](#).

Parameter	Symbol	Min	Typ	Max	Unit
RX_CLK clock period 10 Mbps	t_{MRX}	399.96	400	400.04	ns
RX_CLK clock period 100 Mbps	t_{MRX}	39.996	40	40.004	ns
RX_CLK duty cycle	t_{MRXH}/t_{MRX}	35	—	65	%
RXD[3:0], RX_DV, RX_ER setup time to RX_CLK	t_{MRDVKH}	10.0	—	—	ns
RXD[3:0], RX_DV, RX_ER hold time to RX_CLK	t_{MRDXKH}	10.0	—	—	ns
RX_CLK clock rise (20%-80%)	t_{MRXR}	1.0	—	4.0	ns
RX_CLK clock fall time (80%-20%)	t_{MRXF}	1.0	—	4.0	ns

Note: The frequency of RX_CLK should not exceed frequency of GTX_CLK125 by more than 300ppm.

Electrical characteristics

Table 41. Ethernet management interface 2 AC timing specifications (continued)

For recommended operating conditions, see [Table 3](#).

Parameter/Condition	Symbol ¹	Min	Typ	Max	Unit	Note
MDIO to MDC hold time	t_{MDDXKH}	0	—	—	ns	—

Note:

1. The symbols used for timing specifications follow the pattern of $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. For example, t_{MDKHDX} symbolizes management data timing (MD) for the time t_{MDC} from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t_{MDDVKH} symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MDC} clock reference (K) going to the high (H) state or setup time.
2. This parameter is dependent on the frame manager clock frequency (MIIMCFG [MgmtClk] field determines the clock frequency of the MgmtClk Clock EC_MDC).
3. This parameter is dependent on the management data clock frequency, f_{MDC} . The delay is equal to 0.5 management data clock period ± 6 ns. For example, with a management data clock of 2.5 MHz, the min/max delay is 200 ns ± 6 ns.

This figure shows the Ethernet management interface timing diagram.

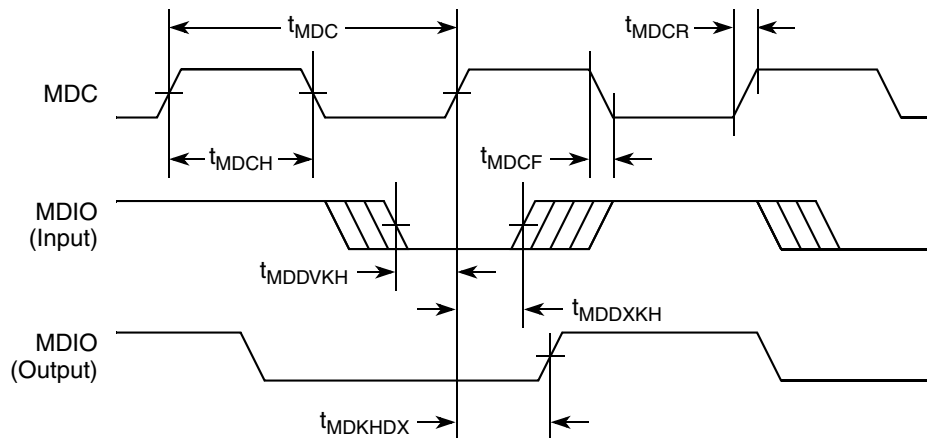


Figure 19. Ethernet management interface timing diagram

2.12.4 eTSEC IEEE Std 1588 timing specifications

This section discusses the electrical characteristics for the eTSEC IEEE Std 1588 interfaces.

2.12.4.1 eTSEC IEEE Std 1588 DC electrical characteristics

This table shows eTSEC IEEE Std 1588 DC electrical characteristics when operating at $V_{DD} = 3.3$ V supply.

Table 42. eTSEC IEEE 1588 DC electrical characteristics ($V_{DD} = 3.3$ V)

For recommended operating conditions, see [Table 3](#).

Parameter	Symbol	Min	Max	Unit	Notes
Input high voltage	V_{IH}	2.0	—	V	2
Input low voltage	V_{IL}	—	0.9	V	2
Input high current ($V_{DD} = \text{Max}$, $V_{IN} = 2.1$ V)	I_{IH}	—	40	μA	1

- For an external AC-coupled connection, there is no common mode voltage requirement for the clock driver. Because the external AC-coupling capacitor blocks the DC level, the clock driver and the SerDes reference clock receiver operate in different common mode voltages. The SerDes reference clock receiver in this connection scheme has its common mode voltage set to SGND. Each signal wire of the differential inputs is allowed to swing below and above the common mode voltage (SGND). [Figure 38](#) shows the SerDes reference clock input requirement for AC-coupled connection scheme.

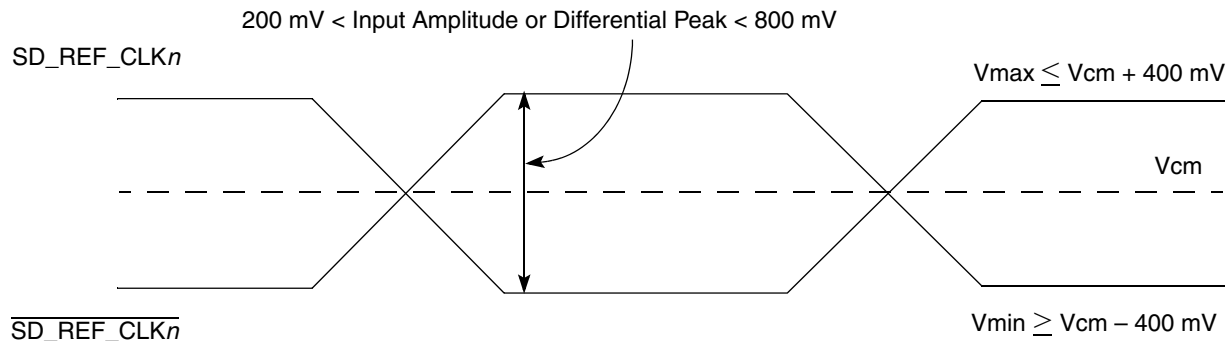


Figure 38. Differential reference clock input DC requirements (external AC-coupled)

- Single-Ended Mode
 - The reference clock can also be single-ended. The SD_REF_CLKn input amplitude (single-ended swing) must be between 400 mV and 800 mV peak-peak (from V_{MIN} to V_{MAX}) with $\overline{\text{SD_REF_CLKn}}$ either left unconnected or tied to ground.
 - The SD_REF_CLKn input average voltage must be between 200 and 400 mV. [Figure 39](#) shows the SerDes reference clock input requirement for single-ended signaling mode.
 - To meet the input amplitude requirement, the reference clock inputs may need to be DC- or AC-coupled externally. For the best noise performance, the reference of the clock could be DC- or AC-coupled into the unused phase ($\overline{\text{SD_REF_CLKn}}$) through the same source impedance as the clock input (SD_REF_CLKn) in use.

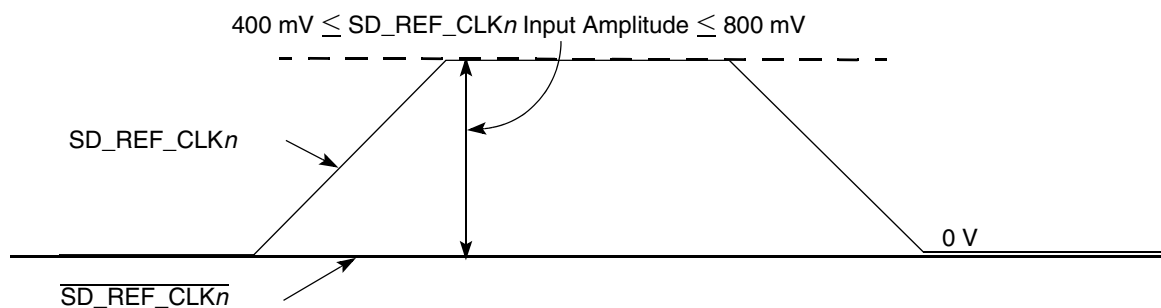


Figure 39. Single-ended reference clock input DC requirements

2.20.2.3 AC requirements for SerDes reference clocks

This table lists AC requirements for the PCI Express, SGMII, Serial RapidIO and Aurora SerDes reference clocks to be guaranteed by the customer's application design.

Table 61. SD_REF_CLKn and SD_REF_CLKn input clock requirements (SV_{DD} = 1.0 V)

For recommended operating conditions, see [Table 3](#).

Parameter	Symbol	Min	Typ	Max	Unit	Notes
SD_REF_CLK/SD_REF_CLK frequency range	t _{CLK_REF}	—	100/125	—	MHz	1
SD_REF_CLK/SD_REF_CLK clock frequency tolerance	t _{CLK_TOL}	−350	—	350	ppm	—
SD_REF_CLK/SD_REF_CLK reference clock duty cycle	t _{CLK_DUTY}	40	50	60	%	4
SD_REF_CLK/SD_REF_CLK max deterministic peak-peak jitter at 10 ^{−6} BER	t _{CLK_DJ}	—	—	42	ps	—
SD_REF_CLK/SD_REF_CLK total reference clock jitter at 10 ^{−6} BER (peak-to-peak jitter at refClk input)	t _{CLK_TJ}	—	—	86	ps	2
SD_REF_CLK/SD_REF_CLK rising/falling edge rate	t _{CLKRRR/t_{CLKFR}}	1	—	4	V/ns	3
Differential input high voltage	V _{IH}	200	—	—	mV	4
Differential input low voltage	V _{IL}	—	—	−200	mV	4
Rising edge rate (SD_REF_CLKn) to falling edge rate (SD_REF_CLKn) matching	Rise-Fall Matching	—	—	20	%	5, 6

Notes:

- Caution:** Only 100 and 125 have been tested. In-between values not work correctly with the rest of the system.
- Limits from PCI Express CEM Rev 2.0
- Measured from −200 mV to +200 mV on the differential waveform (derived from SD_REF_CLKn minus SD_REF_CLKn). The signal must be monotonic through the measurement region for rise and fall time. The 400 mV measurement window is centered on the differential zero crossing. See [Figure 40](#).
- Measurement taken from differential waveform
- Measurement taken from single-ended waveform
- Matching applies to rising edge for SD_REF_CLKn and falling edge rate for SD_REF_CLKn. It is measured using a 200 mV window centered on the median cross point where SD_REF_CLKn rising meets SD_REF_CLKn falling. The median cross point is used to calculate the voltage thresholds that the oscilloscope uses for the edge rate calculations. The rise edge rate of SD_REF_CLKn should be compared to the fall edge rate of SD_REF_CLKn, the maximum allowed difference should not exceed 20% of the slowest edge rate. See [Figure 41](#).

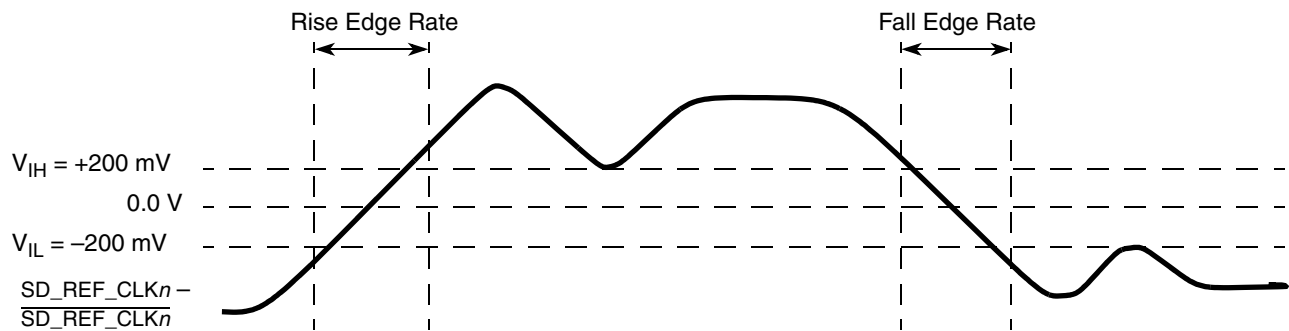


Figure 40. Differential measurement points for rise and fall time

This table defines the PCI Express 2.0 (5 GT/s) DC specifications for the differential output at all transmitters. The parameters are specified at the component pins.

Table 63. PCI Express 2.0 (5 GT/s) differential transmitter output DC specifications
($XV_{DD} = 1.5\text{ V or }1.8\text{ V}$)

For recommended operating conditions, see [Table 3](#).

Parameter	Symbol	Min	Typical	Max	Units	Notes
Differential peak-to-peak output voltage	$V_{TX-DIFFp-p}$	800	—	1200	mV	$V_{TX-DIFFp-p} = 2 \times V_{TX-D+} - V_{TX-D-} $ See Note 1.
Low Power differential peak-to-peak output voltage	$V_{TX-DIFFp-p_low}$	400	500	1200	mV	$V_{TX-DIFFp-p} = 2 \times V_{TX-D+} - V_{TX-D-} $ See Note 1.
De-emphasized differential output voltage (ratio)	$V_{TX-DE-RATIO-3.5dB}$	3.0	3.5	4.0	dB	Ratio of the $V_{TX-DIFFp-p}$ of the second and following bits after a transition divided by the $V_{TX-DIFFp-p}$ of the first bit after a transition. See Note 1.
De-emphasized differential output voltage (ratio)	$V_{TX-DE-RATIO-6.0dB}$	5.5	6.0	6.5	dB	Ratio of the $V_{TX-DIFFp-p}$ of the second and following bits after a transition divided by the $V_{TX-DIFFp-p}$ of the first bit after a transition. See Note 1.
DC differential transmitter impedance	$Z_{TX-DIFF-DC}$	80	100	120	Ω	Transmitter DC differential mode low impedance
Transmitter DC Impedance	Z_{TX-DC}	40	50	60	Ω	Required transmitter D+ as well as D– DC impedance during all states

Note:

1. Measured at the package pins with a test load of 50Ω to GND on each pin.

2.20.4.4 PCI Express DC physical layer receiver specifications

This section discusses the PCI Express DC physical layer receiver specifications 2.5 GT/s, and 5 GT/s.

This table defines the DC specifications for the PCI Express 2.0 (2.5 GT/s) differential input at all receivers. The parameters are specified at the component pins.

Table 64. PCI Express 2.0 (2.5 GT/s) differential receiver input DC specifications ($XV_{DD} = 1.5\text{ V or }1.8\text{ V}$)

For recommended operating conditions, see [Table 3](#).

Parameter	Symbol	Min	Typ	Max	Units	Notes
Differential input peak-to-peak voltage	$V_{RX-DIFFp-p}$	120	—	1200	mV	$V_{RX-DIFFp-p} = 2 \times V_{RX-D+} - V_{RX-D-} $ See Note 1.
DC differential input impedance	$Z_{RX-DIFF-DC}$	80	100	120	Ω	Receiver DC differential mode impedance. See Note 2
DC input impedance	Z_{RX-DC}	40	50	60	Ω	Required receiver D+ as well as D– DC Impedance ($50 \pm 20\%$ tolerance). See Notes 1 and 2.

Table 88. SGMII DC transmitter electrical characteristics ($XV_{DD} = 1.5\text{ V}$ or 1.8 V) (continued)

For recommended operating conditions, see Table 3.

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Output differential voltage ^{2, 3, 4} (XV_{DD-Typ} at 1.5 V and 1.8 V)	$ V_{OD} $	320	500.0	725.0	mV	B(1-3)TECR(lane)0[AMP_RED] =0b000000
		293.8	459.0	665.6		B(1-3)TECR(lane)0[AMP_RED] =0b000010
		266.9	417.0	604.7		B(1-3)TECR(lane)0[AMP_RED] =0b000101
		240.6	376.0	545.2		B(1-3)TECR(lane)0[AMP_RED] =0b001000
		213.1	333.0	482.9		B(1-3)TECR(lane)0[AMP_RED] =0b001100
		186.9	292.0	423.4		B(1-3)TECR(lane)0[AMP_RED] =0b001111
		160.0	250.0	362.5		B(1-3)TECR(lane)0[AMP_RED] =0b010011
Output impedance (single-ended)	R_O	40	50	60	Ω	—

Notes:

1. This does not align to DC-coupled SGMII.
2. $|V_{OD}| = |V_{SD_TXn} - V_{SD_TXn}|$. $|V_{OD}|$ is also referred to as output differential peak voltage. $V_{TX-DIFFp-p} = 2 \cdot |V_{OD}|$.
3. Example amplitude reduction setting for SGMII on SerDes bank 1 lane E: B1TECRE0[AMP_RED] = 0b000010 for an output differential voltage of 459 mV typical.
4. The $|V_{OD}|$ value shown in the Typ column is based on the condition of $XVDD_SRDSn-Typ = 1.5\text{ V}$ or 1.8 V , no common mode offset variation. SerDes transmitter is terminated with 100- Ω differential load between SD_TXn and $\overline{SD_TXn}$.